

## General Description

FSMOS<sup>®</sup>

$R_{DS(ON)}$ , low gate charge, fast switching and excellent avalanche characteristics. The high  $V_{th}$  series is specially optimized for high systems with gate driving voltage greater than 10V.

## Features

- Low  $R_{DS(ON)}$  & FOM
- Extremely low switching loss
- Excellent reliability and uniformity
- Fast switching and soft recovery



## Applications

- Switched mode power supply
- Motor driver
- Battery protection
- DC-DC convertor
- Solar inverter
- UPS and energy inverter

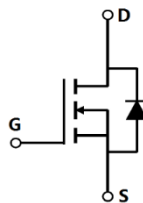
## Key Performance Parameters

| Parameter                      | Value | Unit |
|--------------------------------|-------|------|
| $V_{DS, min} @ T_{j(max)}$     | 60    | V    |
| $I_{D, pulse}$                 | 390   | A    |
| $R_{DS(ON), max} @ V_{GS}=10V$ | 3.0   |      |
| $Q_g$                          | 56.8  | nC   |

## Marking Information

| Product Name | Package | Marking    |
|--------------|---------|------------|
| SFS130N06GF  | PDFN5*6 | SFS130N06G |

## Package & Pin information



**Absolute Maximum Ratings** at  $T_j=25^{\circ}\text{C}$  unless otherwise noted

| Parameter   | Symbol          | Value      | Unit               |
|---|-----------------|------------|--------------------|
| Drain source voltage  | $V_{DS}$        | 60         | V                  |
| Gate source voltage   | $V_{GS}$        | $\pm 20$   | V                  |
| Continuous drain current <sup>1)</sup> , $T_C=25^{\circ}\text{C}$         | $I_D$           | 130        | A                  |
| Pulsed drain current <sup>2)</sup> , $T_C=25^{\circ}\text{C}$             | $I_{D, pulse}$  | 390        | A                  |
| Continuous diode forward current <sup>1)</sup> , $T_C=25^{\circ}\text{C}$ | $I_S$           | 130        | A                  |
| Diode pulsed current <sup>2)</sup> , $T_C=25^{\circ}\text{C}$             | $I_{S, Pulse}$  | 390        | A                  |
| Power dissipation <sup>3)</sup> , $T_C=25^{\circ}\text{C}$                | $P_D$           | 140        | W                  |
| Single pulsed avalanche energy <sup>5)</sup>                              | $E_{AS}$        | 94         | mJ                 |
| Operation and storage temperature   | $T_{stg}$ $T_j$ | -55 to 150 | $^{\circ}\text{C}$ |

**Thermal Characteristics**

| Parameter  | Symbol | Value | Unit                 |
|--|--------|-------|----------------------|
| Thermal resistance, junction-case                  | R      | 0.89  | $^{\circ}\text{C/W}$ |
| Thermal resistance, junction-ambient <sup>4)</sup> | R      | 62    | $^{\circ}\text{C/W}$ |

**Electrical Characteristics** at  $T_j=25^{\circ}\text{C}$  unless otherwise specified

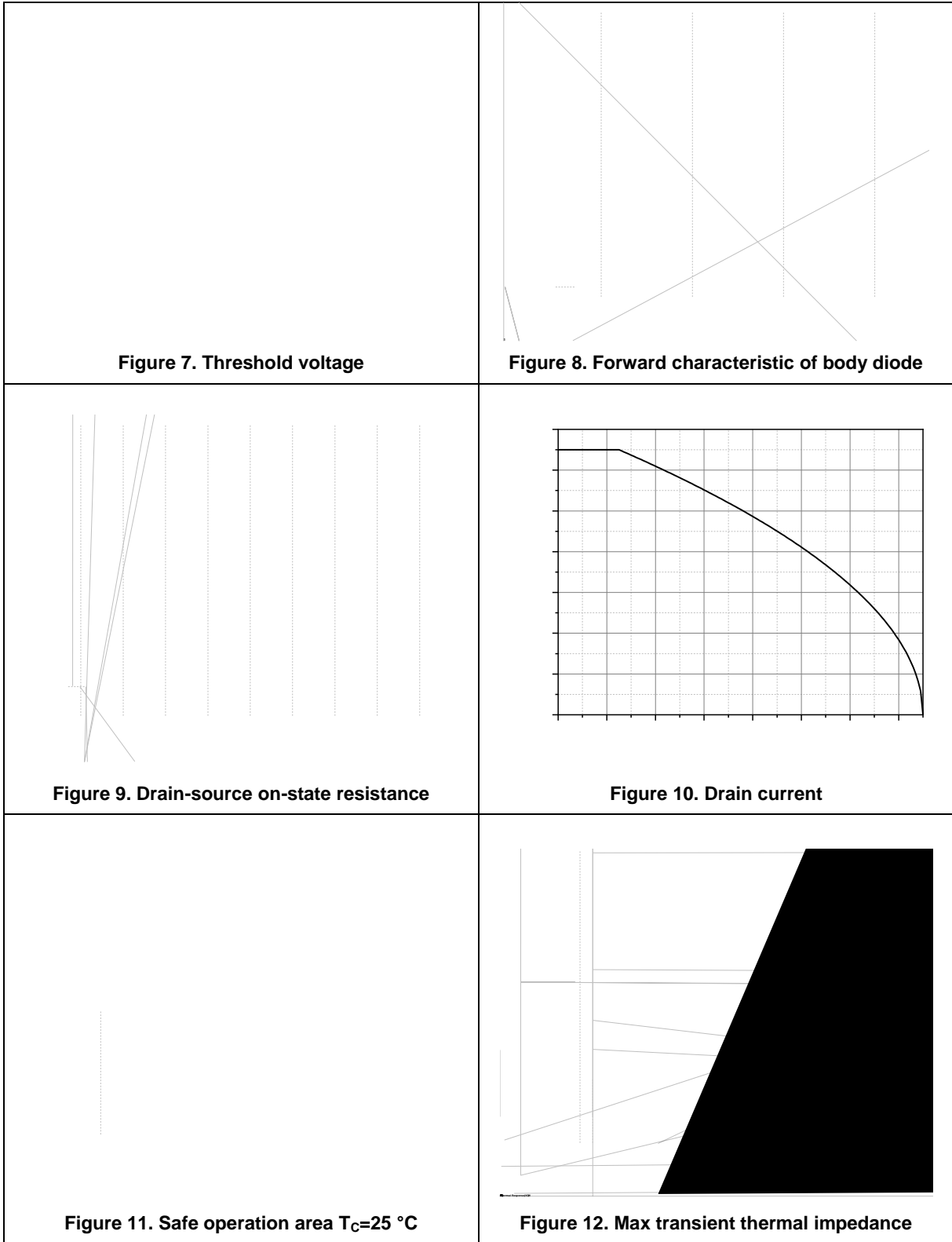
| Parameter                        | Symbol       | Min. | Typ. | Max. | Unit          | Test condition                                     |
|----------------------------------|--------------|------|------|------|---------------|--|
| Drain-source breakdown voltage   | $BV_{DSS}$   | 60   |      |      | V             | $V_{GS}=0\text{ V}$ , $I_D=250\text{ }\mu\text{A}$ |
| Gate threshold voltage           | $V_{GS(th)}$ | 2    |      | 4    | V             | $V_{DS}=V_{GS}$ , $I_D=250\text{ }\mu\text{A}$     |
| Drain-source on-state resistance | $R_{DS(ON)}$ |      | 2.68 | 3.00 |               | $V_{GS}=10\text{ V}$ , $I_D=20\text{ A}$           |
| Gate-source leakage current      | $I_{GSS}$    |      |      | 100  | nA            | $V_{GS}=20\text{ V}$                               |
|                                  |              |      |      | -100 |               | $V_{GS}=-20\text{ V}$                              |
| Drain-source leakage current     | $I_{DSS}$    |      |      | 1    | $\mu\text{A}$ | $V_{DS}=60\text{ V}$ , $V_{GS}=0\text{ V}$         |
| Gate resistance                  | $R_G$        |      | 2.5  |      |               |  |

**Dynamic Characteristics**

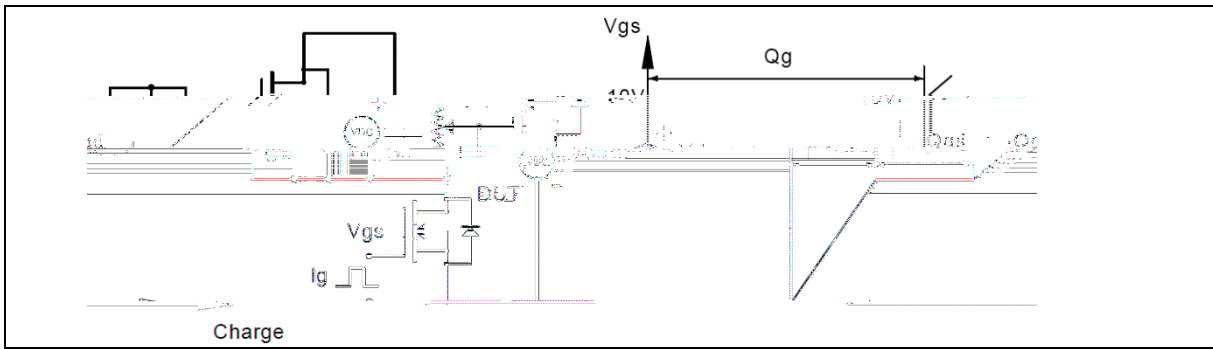
| Parameter                    | Symbol       | Min. | Typ. | Max. | Unit | Test condition   |
|------------------------------|--------------|------|------|------|------|--|
| Input capacitance            | $C_{iss}$    |      | 5411 |      | pF   | $V_{GS}=0\text{ V}$ ,<br>$V_{DS}=25\text{ V}$ ,                                |
| Output capacitance           | $C_{oss}$    |      | 1522 |      | pF   |  |
| Reverse transfer capacitance | $C_{rss}$    |      | 24.2 |      | pF   |  |
| Turn-on delay time           | $t_{d(on)}$  |      | 31.4 |      | ns   | $V_{GS}=10\text{ V}$ ,<br>$V_{DS}=50\text{ V}$ ,<br>$R_G$<br>$I_D=50\text{ A}$ |
| Rise time                    | $t_r$        |      | 54.8 |      | ns   |  |
| Turn-off delay time          | $t_{d(off)}$ |      | 60.5 |      | ns   |  |
| Fall time                    | $t_f$        |      |      |      |      |  |

**Electrical Characteristics Diagrams**

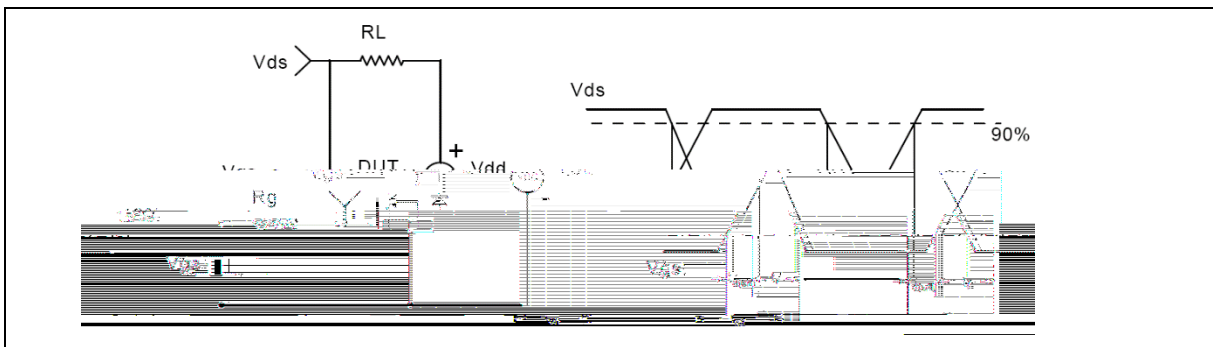
|  |   |
|--|---|
| <p><b>Figure 1. Typ. output characteristics</b></p>    | <p><b>Figure 2. Typ. transfer characteristics</b></p>         |
| <p><b>Figure 3. Typ. capacitances</b></p>              | <p><b>Figure 4. Typ. gate charge</b></p>                      |
| <p><b>Figure 5. Drain-source breakdown voltage</b></p> | <p><b>Figure 6. Drain-source</b> o84 165.26 226.22 16.326</p> |



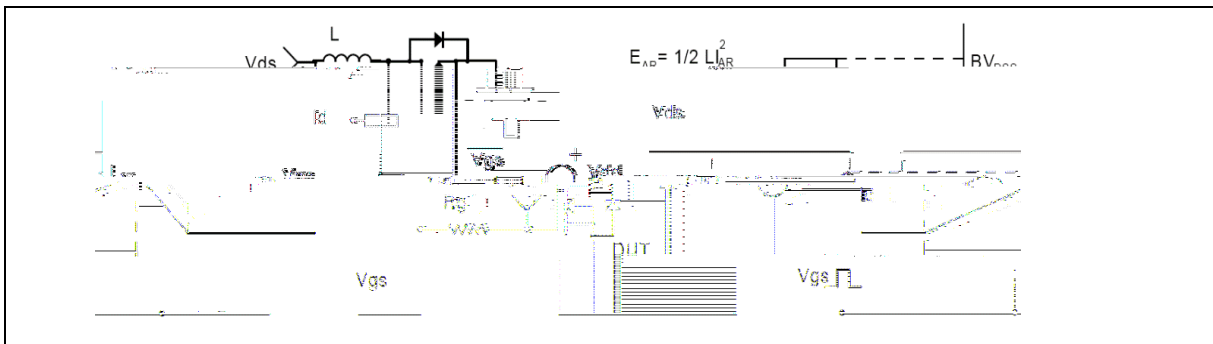
**Test circuits and waveforms**



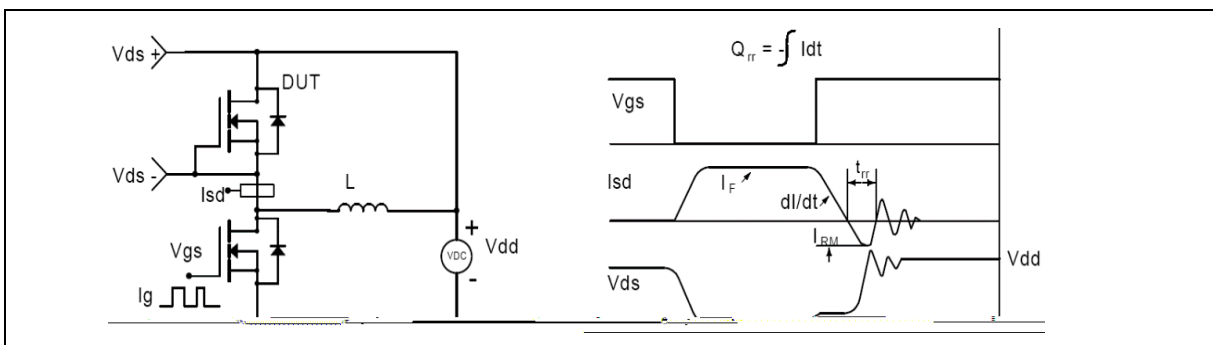
**Figure 1. Gate charge test circuit & waveform**



**Figure 2. Switching time test circuit & waveforms**

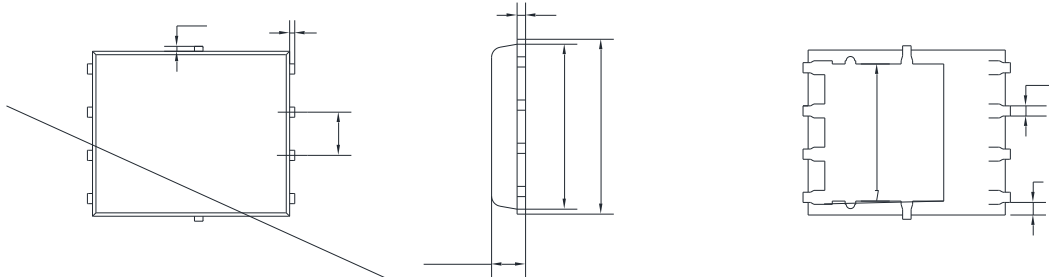


**Figure 3. Unclamped inductive switching (UIS) test circuit & waveforms**



**Figure 4. Diode reverse recovery test circuit & waveforms**

**Package Information**



| Symbol | mm       |      |      |
|--------|----------|------|------|
|        | Min      | Nom  | Max  |
| A      | 0.90     | 1.00 | 1.10 |
| b      | 0.15     | 0.25 | 0.35 |
| c      | 4.70     | 4.90 | 5.10 |
| c1     | 5.00     | 5.20 | 5.40 |
| D      | 3.61     | 3.81 | 4.01 |
| E      | 5.60     | 5.80 | 6.00 |
| E1     | 5.90     | 6.10 | 6.30 |
| E2     | 0.20     | 0.30 | 0.40 |
| E3     | 0.53     | 0.63 | 0.73 |
| E4     | 0.25     | 0.35 | 0.45 |
| e      | 1.17     | 1.27 | 1.37 |
| L1     | 0.05     | 0.15 | 0.25 |
| F      | 0.63 BSC |      |      |
| G      | 3.50 BSC |      |      |
|        | 8°       | 10°  | 12°  |

Version 1: PDFN5\*6-F package outline dimension

